NSN 5961-01-339-6775

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-6775 **Inclosure Material:** Glass **Overall Length:** Between 0.205 inches and 0.225 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Mounting Method:** Press fit **Features Provided:** Burn in and hermetically sealed case and quality assurance level txv **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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